

# SPICE Device Model Si4922BDY

## **Vishay Siliconix**

# **Dual N-Channel 30V (D-S) MOSFET**

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

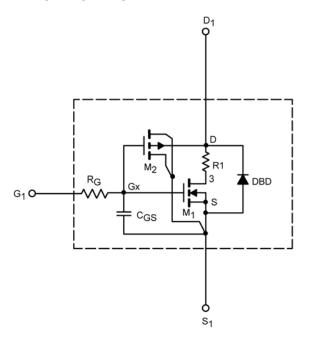
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

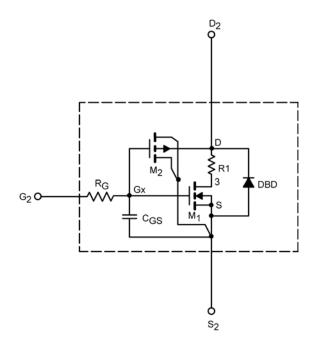
#### **DESCRIPTION**

The attached spice model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to  $125^{\circ}$ C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC





This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T <sub>J</sub> = 25°C UN	NLESS OTHERV	VISE NOTED)			
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.90		V
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	354		Α
Drain-Source On-State Resistance <sup>a</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 5 A	0.0137	0.0135	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 5 \text{ A}$	0.0150	0.0145	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 5 A	30	30	S
Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 1.7 A	0.74	0.77	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz	2459	2070	pF
Output Capacitance	Coss		254	255	
Reverse Transfer Capacitance	C <sub>rss</sub>		107	135	
Total Gate Charge	$Q_g$	$V_{DS}$ = 15 V, $V_{GS}$ = 10 V, $I_D$ = 5 A	36	41	nC
		$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_{D}$ = 5 A	18	19	
Gate-Source Charge	$Q_{gs}$		3.5	3.5	
Gate-Drain Charge	$Q_{gd}$		3.7	3.7	

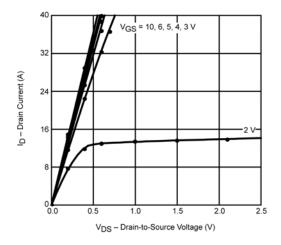
a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2\%.$  b. Guaranteed by design, not subject to production testing.

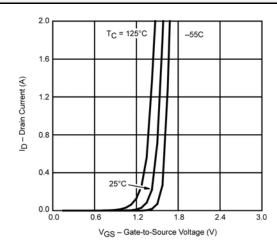


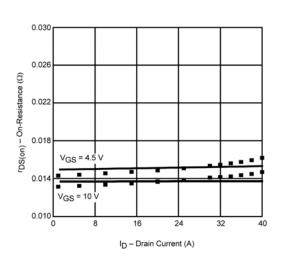
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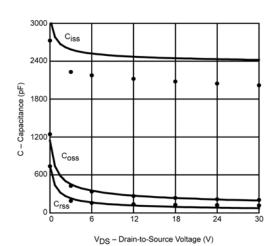
#### COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

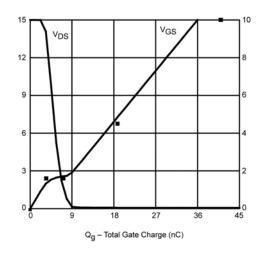
<sup>r</sup>DS(on) – On-Resistance (Ω)

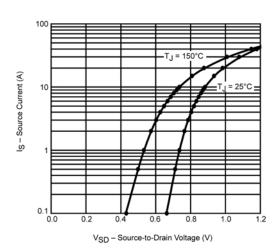












Note: Dots and squares represent measured data.



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